| Parameter | Tr1 and Tr2 |
|------------------|-------------|
| V _{CEO} | 20V |
| V _{EBO} | 12V |
| Ι _C | 600mA |
| R ₁ | 10kΩ |

Features

- 1) Built-In Biasing Resistors
- 2) Two DTC614T chips in one package.
- Low saturation voltage, typically V_{CE(sat)} =40mV at I_C / I_B=50mA / 2.5mA, makes these transistors ideal for muting circuits.
- 4) These transistors can be used at high current levels, $\rm I_{C}=600mA.$
- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit).
- 6) The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of completely eliminating parasitic effects.

Package

SMT6

Package

size

(mm)

2928

7) Lead Free/RoHS Compliant.

Application

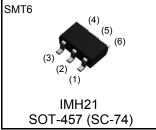
Muting circuit

Packaging specifications

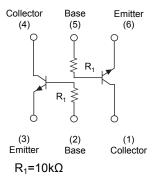
Part No.

IMH21

| Out | ine |
|-----|-----|
| | |



Inner circuit



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|--|--|
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Taping

code

T110

Reel size

(mm)

180

Tape width

(mm)

8

Marking

H21

Basic

ordering

unit (pcs)

3.000

●Absolute maximum ratings (Ta = 25°C)

<For Tr1 and Tr2 in common>

| Parameter | Symbol | Values | Unit |
|------------------------------|------------------------------|--------------------------|------|
| Collector-base voltage | V _{CBO} | 20 | V |
| Collector-emitter voltage | V _{CEO} | 20 | V |
| Emitter-base voltage | V _{EBO} | 12 | V |
| | Ι _C | 600 | mA |
| Collector current | I _{CP} *1 | 1 | А |
| Power dissipation | P _D ^{*2} | 300(Total) ^{*3} | mW |
| Junction temperature | Tj | 150 | °C |
| Range of storage temperature | T _{stg} | –55 to +150 | °C |

•Electrical characteristics (Ta = 25°C)

<For Tr1 and Tr2 in common>

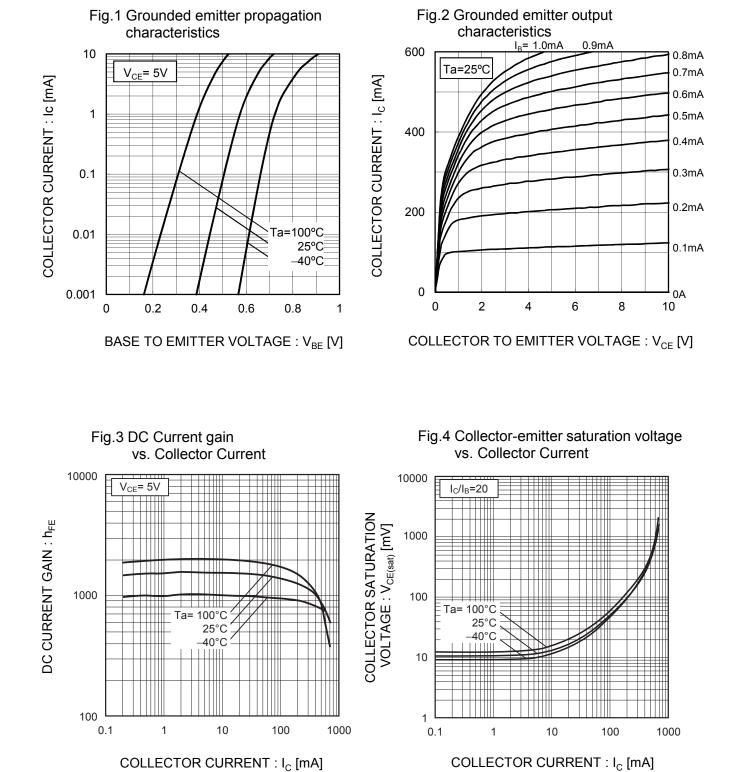
| Parameter | Symbol | Conditions | Min. | Тур. | Max. | Unit |
|--------------------------------------|----------------------|---|------|------|------|------|
| Collector-base breakdown voltage | BV _{CBO} | I _C = 50μΑ | 20 | - | - | V |
| Collector-emitter breakdown voltage | BV _{CEO} | I _C = 1mA | 20 | - | - | V |
| Emitter-base breakdown voltage | BV _{EBO} | I _E = 50μA | 12 | - | - | V |
| Collector cut-off current | I _{CBO} | V _{CB} = 20V | - | - | 0.5 | μA |
| Emitter cut-off current | I _{EBO} | V _{EB} = 12V | - | - | 0.5 | μA |
| Collector-emitter saturation voltage | V _{CE(sat)} | I _C / I _B = 50mA / 2.5mA | - | 40 | 150 | mV |
| DC current gain | h _{FE} | V _{CE} = 5V, I _C = 50mA | 820 | - | 2700 | - |
| Input resistance | R ₁ | - | 7 | 10 | 13 | kΩ |
| Transition frequency | f _T *4 | V _{CE} = 10V, I _E = –50mA f = 100MHz | - | 150 | - | MHz |
| Output ON Resistance | R _{on} | V _I = 5V R _L = 1kΩ, f = 1kHz | - | 0.9 | - | Ω |

*1 P_W =10ms, Single pulse

*2 Each terminal mounted on a reference footprint

*3 200mW per element must not be exceeded.

*4 Characteristics of built-in transistor



•Electrical characteristic curves(Ta = 25°C)

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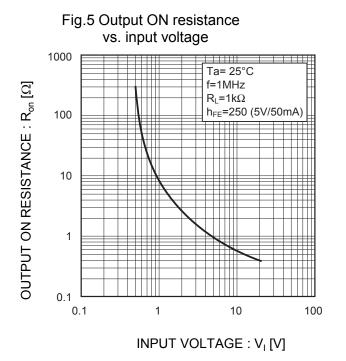
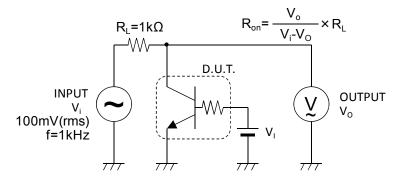


Fig.6 Ron measurement circuit.

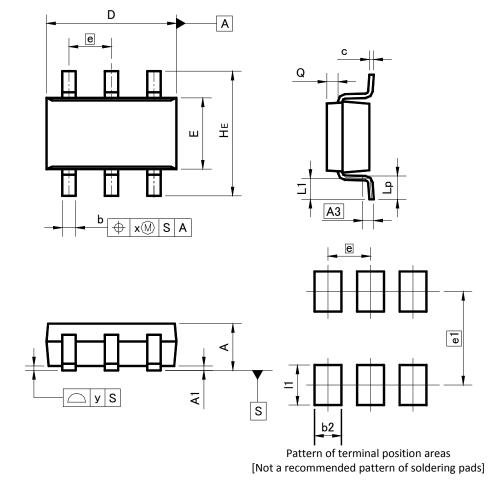


4/5



•Dimensions (Unit : mm)

SMT6



| | MILIMETERS | | INC | HES |
|-----|------------|------|-------|-------|
| DIM | MIN | MAX | MIN | MAX |
| A | 1.00 | 1.30 | 0.039 | 0.051 |
| A1 | 0.00 | 0.10 | 0.000 | 0.004 |
| A3 | 0.2 | 25 | 0.0 | 10 |
| b | 0.25 | 0.40 | 0.010 | 0.016 |
| с | 0.09 | 0.25 | 0.004 | 0.010 |
| D | 2.80 | 3.00 | 0.110 | 0.118 |
| E | 1.50 | 1.80 | 0.059 | 0.071 |
| е | 0.95 | | 0.037 | |
| HE | 2.60 | 3.00 | 0.102 | 0.118 |
| L1 | 0.30 | 0.60 | 0.012 | 0.024 |
| Lp | 0.40 | 0.70 | 0.016 | 0.028 |
| Q | 0.20 | 0.30 | 0.008 | 0.012 |
| x | _ | 0.20 | _ | 0.008 |
| У | _ | 0.10 | _ | 0.004 |

| DIM | MILIMETERS | | INC | HES |
|-----|------------|------|-----|-------|
| DIM | MIN | MAX | MIN | MAX |
| b2 | | 0.60 | - | 0.024 |
| e1 | 2. | 10 | 0.0 | 83 |
| 1 | - | 0.90 | - | 0.035 |

Dimension in mm / inches

| | Notes |
|-----|--|
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IMH21 - Web Page

Distribution Inventory

| Part Number | IMH21 |
|-----------------------------|---------|
| Package | SMT6 |
| Unit Quantity | 3000 |
| Minimum Package Quantity | 3000 |
| Packing Type | Taping |
| Constitution Materials List | inquiry |
| RoHS | Yes |